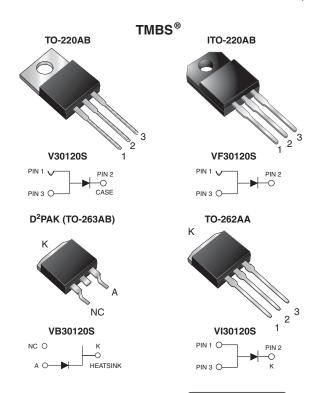
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High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.43 \text{ V}$ at $I_F = 5 \text{ A}$



DESIGN SUPPORT TOOLS

Models



PRIMARY CHARACTERISTICS						
I _{F(AV)}	30 A					
V _{RRM}	120 V					
I _{FSM}	300 A					
V _F at I _F = 30 A	0.74 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Single					

FEATURES

Trench MOS Schottky technology



· Low forward voltage drop, low power losses

· High efficiency operation

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)

RoHS

- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, TO-262AA package)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D2PAK (TO-263AB), and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V30120S	VF30120S	VB30120S	VI30120S	UNIT	
Maximum repetitive peak reverse voltage	V _{RRM}	120				V	
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	30			Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	300			Α		
Non-repetitive avalanche energy at T _J = 25 °C, L = 100 mH	E _{AS}	180			mJ		
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C	I _{RRM}	0.5			Α		
Voltage rate of change (rated V _R)	dV/dt	10 000			V/µs		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			V		
Operating junction and storage temperature range	T _J , T _{STG}	-40 to +150			°C		

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Instantaneous forward voltage per diode (1)	I _F = 5 A		V_F	0.50	-	V		
	I _F = 15 A	T _A = 25 °C		0.70	-			
	I _F = 30 A			0.99	1.10			
	I _F = 5 A			0.43	-	V		
	I _F = 15 A	T _A = 125 °C		0.60	-	İ		
	I _F = 30 A			0.74	0.82			
Reverse current per diode (2)	V _R = 90 V	T _A = 25 °C	I _R	18	-	μΑ		
		T _A = 125 °C		12	-	mA		
	V _R = 120 V	T _A = 25 °C		-	500	μΑ		
		T _A = 125 °C		22	35	mA		

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

 $^{(2)}$ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V30120S	VF30120S	VB30120S	VI30120S	UNIT	
Typical thermal resistance per diode	$R_{ heta JC}$	1.6	4.0	1.6	1.6	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V30120S-E3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VF30120S-E3/4W	1.75	4W	50/tube	Tube			
TO-263AB	VB30120S-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VB30120S-E3/8W	1.39	8W	800/reel	Tape and reel			
TO-262AA	VI30120S-E3/4W	1.46	4W	50/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

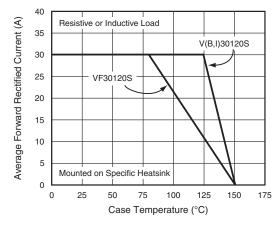


Fig. 1 - Forward Current Derating Curve

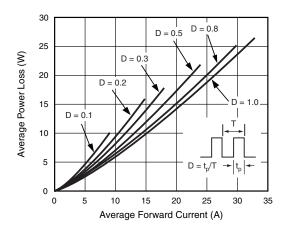


Fig. 2 - Forward Power Loss Characteristics Per Diode

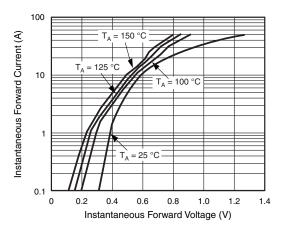


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

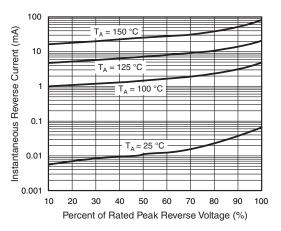


Fig. 4 - Typical Reverse Characteristics Per Diode

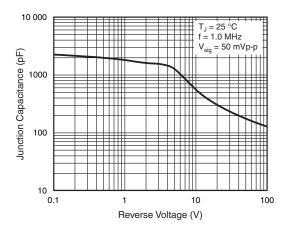


Fig. 5 - Typical Junction Capacitance Per Diode

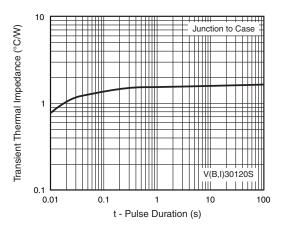


Fig. 6 - Typical Transient Thermal Impedance Per Diode

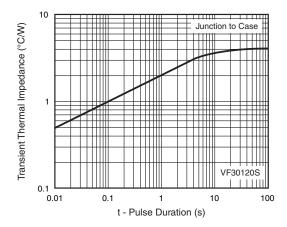
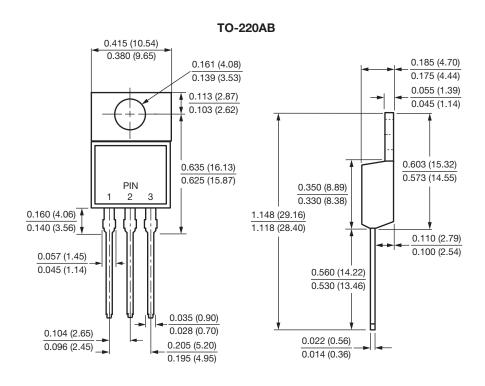


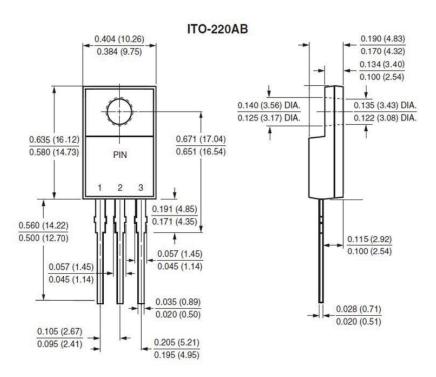
Fig. 7 - Typical Transient Thermal Impedance Per Diode

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



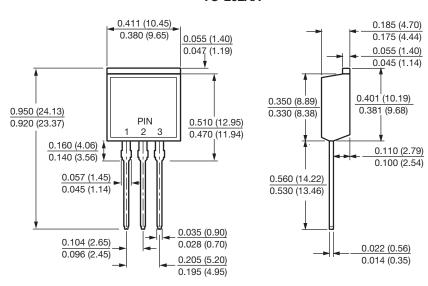


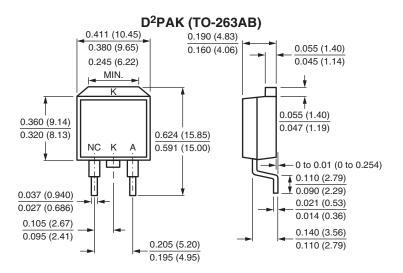
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V30120S-E3, VF30120S-E3, VB30120S-E3, VI30120S-E3

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TO-262AA





0.42 (10.66) MIN. 0.670 (17.02) 0.591 (15.00) 0.08 (2.032) MIN. 0.08 (2.032) MIN. 0.105 (2.67) 0.095 (2.41)



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